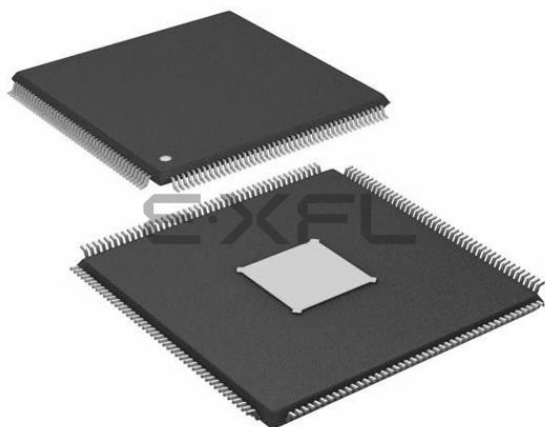




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"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Active
Core Processor	e200z2, e200z4, e200z4
Core Size	32-Bit Tri-Core
Speed	80MHz/120MHz
Connectivity	CANbus, Ethernet, I ² C, LINbus, SAI, SPI, USB, USB OTG
Peripherals	DMA, LVD, POR, WDT
Number of I/O	129
Program Memory Size	4MB (4M x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	768K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 80x10b, 64x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	176-LQFP Exposed Pad
Supplier Device Package	176-LQFP (24x24)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/spc5747gk1cku2

1 Block diagram

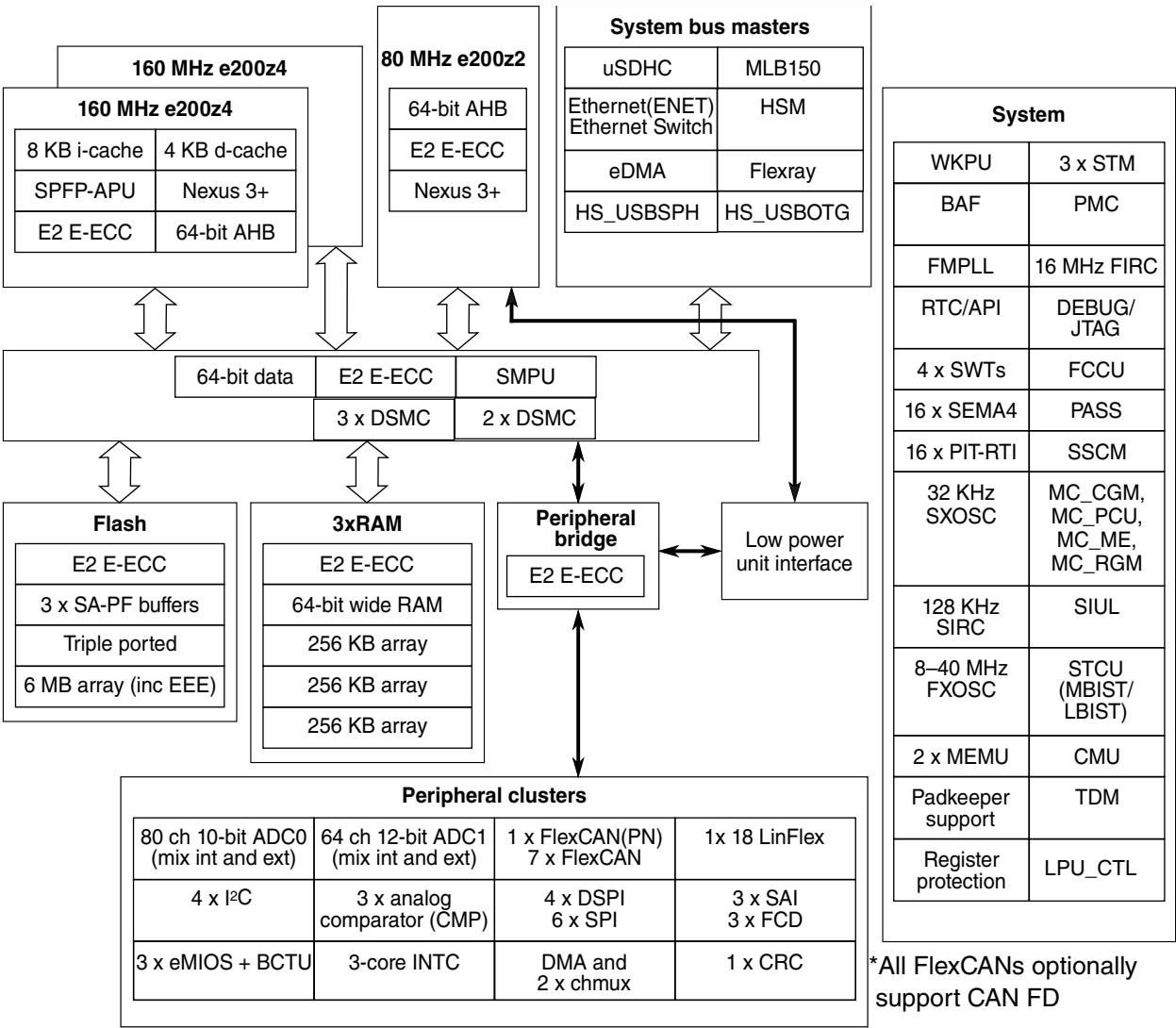


Figure 1. MPC5748G block diagram

2 Family comparison

The following table provides a summary of the different members of the MPC5748G family and their proposed features. This information is intended to provide an understanding of the range of functionality offered by this family. For full details of all of the family derivatives please contact your marketing representative.

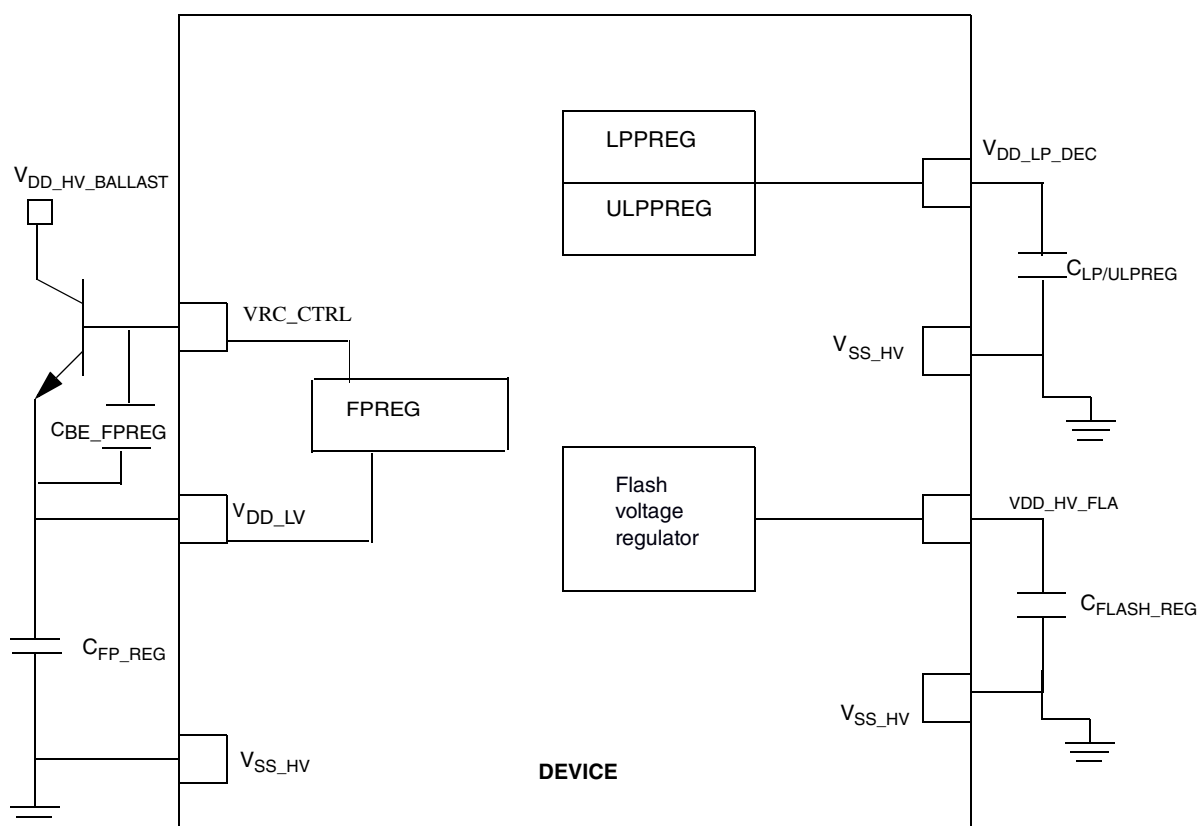


Figure 2. Voltage regulator capacitance connection

Table 8. Voltage regulator electrical specifications

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
C_{fp_reg} ¹	External decoupling / stability capacitor	Min, max values shall be granted with respect to tolerance, voltage, temperature, and aging variations.	1.32	2.2 ²	3	μF
	Combined ESR of external capacitor	—	0.001	—	0.03	Ohm
C_{lp/ulp_reg}	External decoupling / stability capacitor for internal low power regulators	Min, max values shall be granted with respect to tolerance, voltage, temperature, and aging variations.	0.8	1	1.4	μF
	Combined ESR of external capacitor	—	0.001	—	0.1	Ohm
C_{be_fpreg} ³	Capacitor in parallel to base-emitter	BCP68 and BCP56		3.3		nF
		MJD31		4.7		
C_{flash_reg} ⁴	External decoupling / stability capacitor for internal Flash regulators	Min, max values shall be granted with respect to tolerance, voltage, temperature, and aging variations.	1.32	2.2	3	μF
	Combined ESR of external capacitor	—	0.001	—	0.03	Ohm

Table continues on the next page...

7. In external ballast configuration the following must be ensured during power-up and power-down (Note: If $V_{DD_HV_BALLAST}$ is supplied from the same source as $V_{DD_HV_A}$ this condition is implicitly met):
- During power-up, $V_{DD_HV_BALLAST}$ must have met the min spec of 2.25V before $V_{DD_HV_A}$ reaches the POR_HV_RISE min of 2.75V.
 - During power-down, $V_{DD_HV_BALLAST}$ must not drop below the min spec of 2.25V until $V_{DD_HV_A}$ is below POR_HV_FALL min of 2.7V.

NOTE

For a typical configuration using an external ballast transistor with separate supply for $V_{DD_HV_A}$ and the ballast collector, a bulk storage capacitor (as defined in [Table 8](#)) is required on $V_{DD_HV_A}$ close to the device pins to ensure a stable supply voltage.

Extra care must be taken if the $V_{DD_HV_A}$ supply is also being used to power the external ballast transistor or the device is running in internal regulation mode. In these modes, the inrush current on device Power Up or on exit from Low Power Modes is significant and may cause the $V_{DD_HV_A}$ voltage to drop resulting in an LVD reset event. To avoid this, the board layout should be optimized to reduce common trace resistance or additional capacitance at the ballast transistor collector (or $V_{DD_HV_A}$ pins in the case of internal regulation mode) is required. NXP recommends that customers simulate the external voltage supply circuitry.

In all circumstances, the voltage on $V_{DD_HV_A}$ must be maintained within the specified operating range (see [Recommended operating conditions](#)) to prevent LVD events.

4.4 Voltage monitor electrical characteristics

Table 9. Voltage monitor electrical characteristics

Symbol	Parameter	State	Conditions	Configuration			Threshold			Unit
				Power Up ¹	Mask Opt	Reset Type	Min	Typ	Max	
V_{POR_LV}	LV supply power on reset detector	Fall	Untrimmed	Yes	No	Powerup	0.930	0.979	1.028	V
			Trimmed				0.959	0.979	0.999	V
		Rise	Untrimmed				0.980	1.029	1.078	V
			Trimmed				1.009	1.029	1.049	V

Table continues on the next page...

General

- x FlexCAN state machines clocked (other FLEXCAN clock gated), 4 x LINFlexD transmitting (Other clock gated), 1x eMIOS clocked (used OPWFMB mode) (Others clock gated), FIRC, SIRC, FXOSC, SXOSC, PLL running, BCTU, DMAMUX, ACOMP clock gated. All others modules clock gated if not specifically mentioned. I/O supply current excluded
6. Recommended Transistors: MJD31 @ 85°C, 105°C and 125°C.
 7. Enabled Modules in Body mode enabled at maximum frequency: 2 x e200Z4 @ 120Mhz (Instruction and Data cache enabled), Platform @ 120MHz, SRAMs accessed in parallel, Flash access (prefetch is disabled while buffers are enabled), HSM reading from flash at regular intervals (500 pll clock cycles), DMA (SRAM to SRAM), ADC0 converting using BCTU triggers which are triggered through PIT (ADC1 clocked), RTC clocked, 3 x STM clocked, 2 x DSPI transmitting (others DSPIs clocked), 2 x SPI transmitting (others clocked), 4 x FlexCAN state machines working (others clocked), 9x LINFlexD transmitting (others clocked), 1x eMIOS operational (used OPWFMB mode) (others clocked), FIRC, SIRC, FXOSC, SXOSC, PLL running, MEMU, FCCU, SIUL, SDHC, CMP clocked, e200Z2, ENET, MLB, SAI, I2C, FlexRay, USB clock gated. All others modules clock gated if not specifically mentioned I/O supply current excluded
 8. Recommended Transistors: BCP56, BCP68 or MJD31 @ 85°C, BCP56, BCP68 or MJD31 @ 105°C and MJD31 @ 125°C.
 9. Enabled Modules in Body mode enabled at maximum frequency: 2 x e200Z4 @ 80Mhz (Instruction and Data cache enabled), Platform @ 80MHz, SRAMs accessed in parallel, Flash access (prefetch is disabled while buffers are enabled), HSM reading from flash at regular intervals (500 pll clock cycles), DMA (SRAM to SRAM), ADC0 converting using BCTU triggers which are triggered through PIT (ADC1 clocked), RTC clocked, 3 x STM clocked, 2 x DSPI transmitting (others DSPIs clocked), 2 x SPI transmitting (others clocked), 4 x FlexCAN state machines working (others clocked), 9x LINFlexD transmitting (others clocked), 1x eMIOS operational (used OPWFMB mode) (others clocked), FIRC, SIRC, FXOSC, SXOSC, PLL running, MEMU, FCCU, SIUL, SDHC, CMP clocked, e200Z2, ENET, MLB, SAI, I2C, FlexRay, USB clock gated. All others modules clock gated if not specifically mentioned I/O supply current excluded
 10. Recommended Transistors: BCP56, BCP68 or MJD31 @ 85°C, 105°C and 125°C
 11. Internal structures hold the input voltage less than $V_{DD_HV_ADC_REF} + 1.0$ V on all pads powered by V_{DDA} supplies, if the maximum injection current specification is met (3 mA for all pins) and V_{DDA} is within the operating voltage specifications.
 12. This value is the total current for two ADCs. Each ADC might consume up to 2mA at max.

Table 11. Low Power Unit (LPU) Current consumption characteristics

Symbol	Parameter	Conditions ¹	Min	Typ	Max	Unit
LPU_RUN	with 256K RAM, but only one RAM being accessed	$T_a = 25^\circ\text{C}$ SYS_CLK = 16MHz ADC0 = OFF, SPI0 = OFF, LIN0 = OFF, CAN0 = OFF	—	8.9		mA
		$T_a = 25^\circ\text{C}$ SYS_CLK = 16MHz ADC0 = ON, SPI0 = ON, LIN0 = ON, CAN0 = ON		10.2		
		$T_a = 85^\circ\text{C}$	—	12.5	22	
		$T_a = 105^\circ\text{C}$	—	14.5	24	
		$T_a = 125^\circ\text{C}$ ² SYS_CLK = 16MHz ADC0 = ON, SPI0 = ON, LIN0 = ON, CAN0 = ON	—	16	26	
LPU_STOP	with 256K RAM	$T_a = 25^\circ\text{C}$	—	0.535		mA
		$T_a = 85^\circ\text{C}$	—	0.72	6	
		$T_a = 105^\circ\text{C}$	—	1	8	
		$T_a = 125^\circ\text{C}$ ²	—	1.6	10.6	

1. The content of the Conditions column identifies the components that draw the specific current.
2. Assuming $T_a = T_j$, as the device is in static (fully clock gated) mode. Assumes maximum θ_{JA} of 2s2p board. See [Thermal attributes](#)

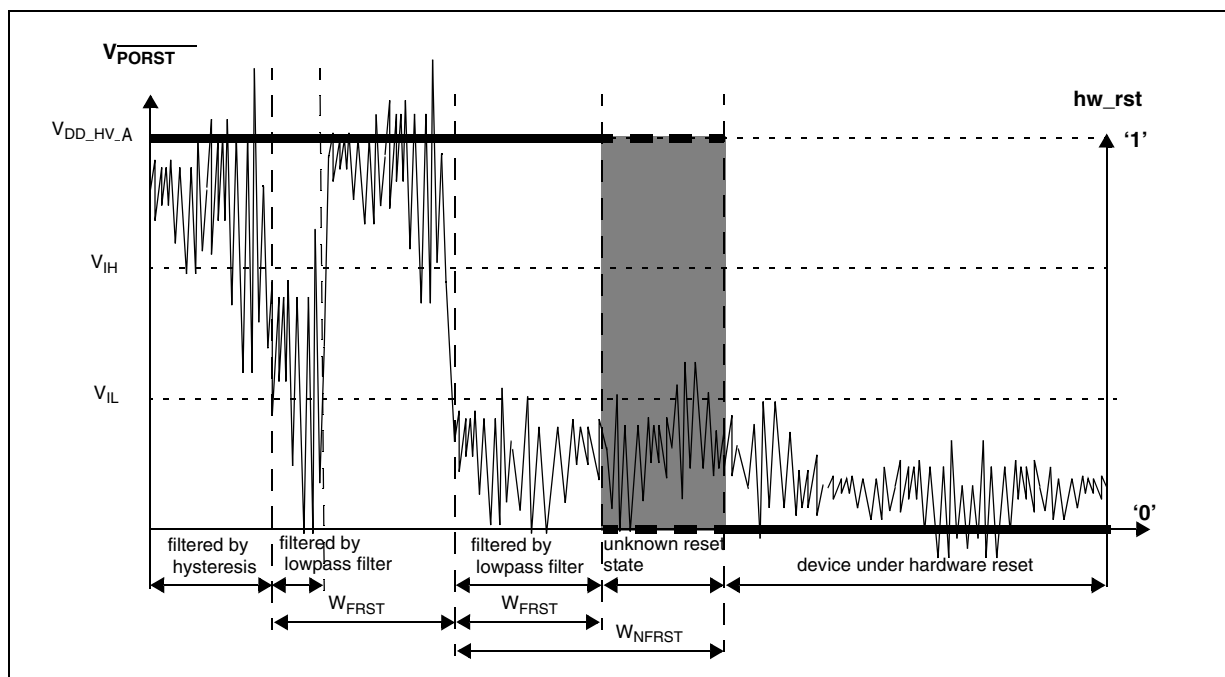


Figure 4. Noise filtering on reset signal

Table 18. Functional reset pad electrical specifications

Symbol	Parameter	Conditions	Value			Unit
			Min	Typ	Max	
V _{IH}	Input high level TTL (Schmitt Trigger)	—	2.0	—	V _{DD_HV_A} + 0.4	V
V _{IL}	Input low level TTL (Schmitt Trigger)	—	−0.4	—	0.8	V
V _{HYS}	Input hysteresis TTL (Schmitt Trigger)	—	300	—	—	mV
V _{DD_POR}	Minimum supply for strong pull-down activation	—	—	—	1.2	V
I _{OL_R}	Strong pull-down current ¹	Device under power-on reset V _{DD_HV_A} = V _{DD_POR} V _{OL} = 0.35 * V _{DD_HV_A}	0.2	—	—	mA
		Device under power-on reset V _{DD_HV_A} = V _{DD_POR} V _{OL} = 0.35 * V _{DD_HV_IO}	11	—	—	mA
W _{FRST}	RESET input filtered pulse	—	—	—	500	ns
W _{NFRST}	RESET input not filtered pulse	—	2000	—	—	ns
I _{WPUL}	Weak pull-up current absolute value	RESET pin V _{IN} = V _{DD}	23	—	82	μA

1. Strong pull-down is active on PHASE0, PHASE1, PHASE2, and the beginning of PHASE3 for RESET.

6.1.1.1 Input equivalent circuit and ADC conversion characteristics

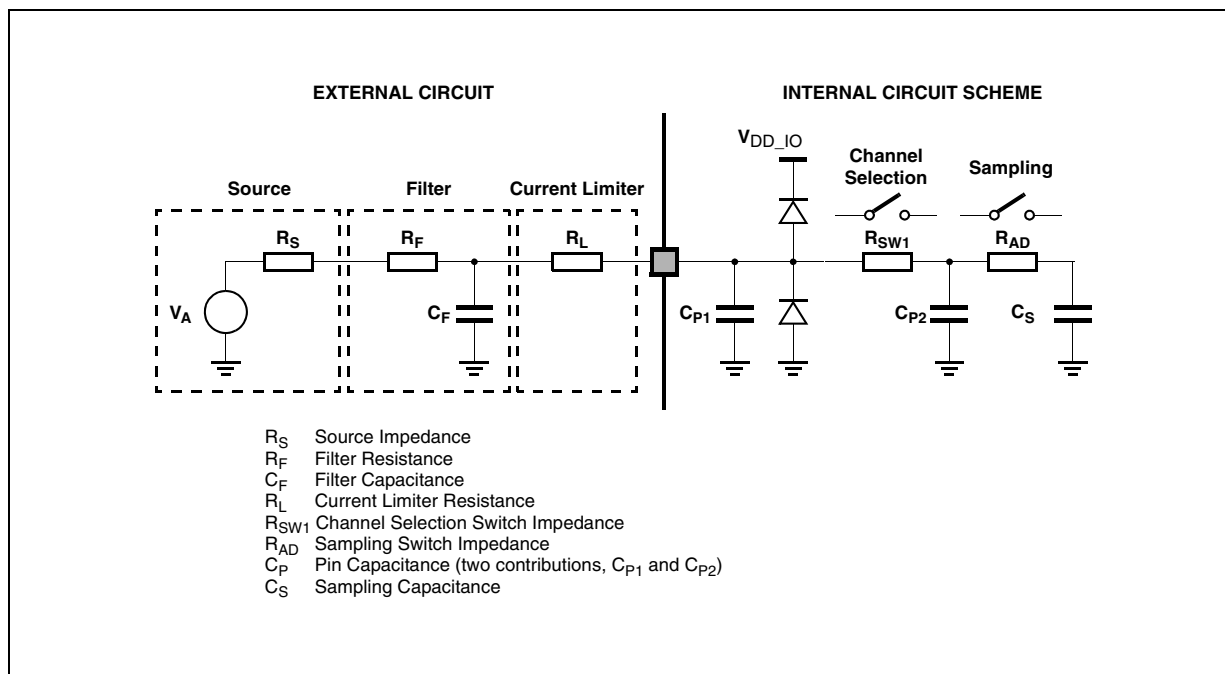


Figure 6. Input equivalent circuit

NOTE

The ADC performance specifications are not guaranteed if two ADCs simultaneously sample the same shared channel.

Table 20. ADC conversion characteristics (for 12-bit)

Symbol	Parameter	Conditions	Min	Typ ¹	Max	Unit
f_{CK}	ADC Clock frequency (depends on ADC configuration) (The duty cycle depends on AD_CK ² frequency)	—	15.2	80	80	MHz
f_s	Sampling frequency	80 MHz	—	—	1.00	MHz
t_{sample}	Sample time ³	80 MHz @ 100 ohm source impedance	250	—	—	ns
t_{conv}	Conversion time ⁴	80 MHz	700	—	—	ns
t_{total_conv}	Total Conversion time $t_{sample} + t_{conv}$ (for standard and extended channels)	80 MHz	1.5 ⁵	—	—	μ s
	Total Conversion time $t_{sample} + t_{conv}$ (for precision channels)		1	—	—	
C_S	ADC input sampling capacitance	—	—	3	5	pF
C_{P1} ⁶	ADC input pin capacitance 1	—	—	—	5	pF
C_{P2} ⁶	ADC input pin capacitance 2	—	—	—	0.8	pF
R_{SW1} ⁶	Internal resistance of analog source	V_{REF} range = 4.5 to 5.5 V	—	—	0.3	k Ω
		V_{REF} range = 3.15 to 3.6 V	—	—	875	Ω

Table continues on the next page...

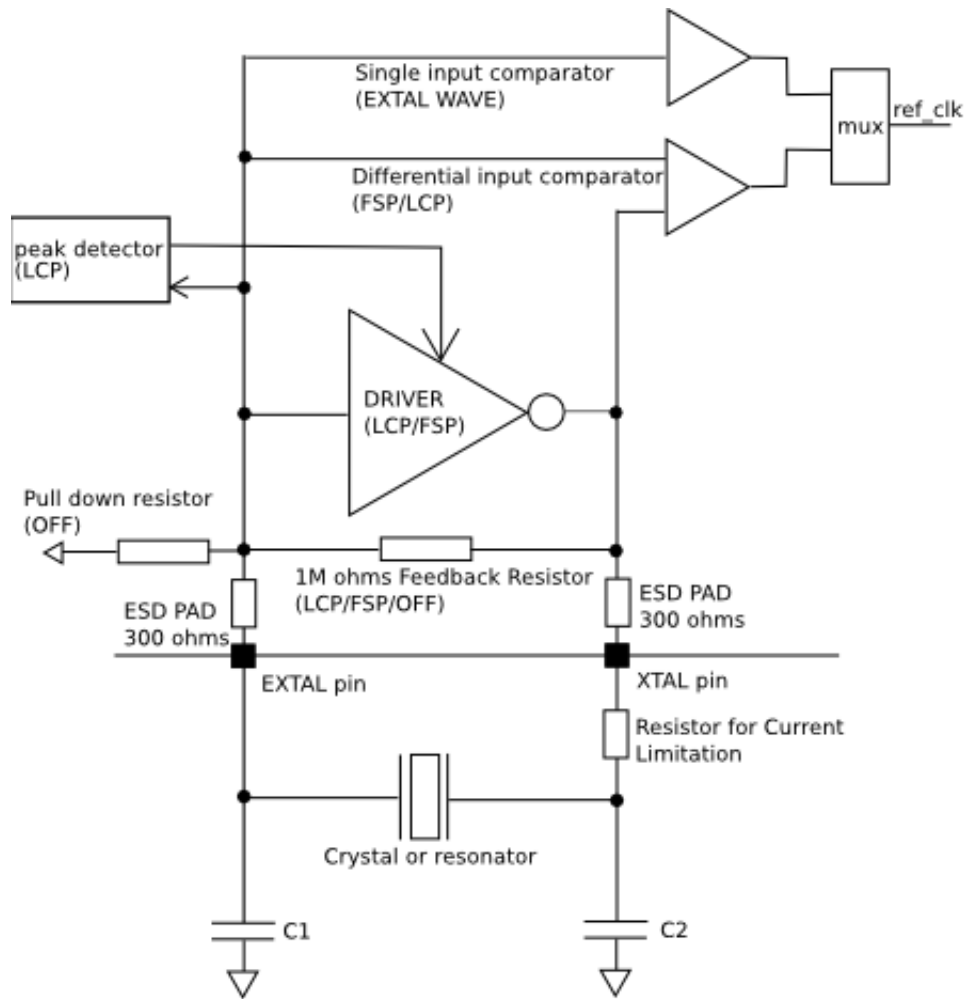


Figure 7. Oscillator connections scheme

Table 23. Main oscillator electrical characteristics

Symbol	Parameter	Mode	Conditions	Min	Typ	Max	Unit
f_{XOSCHS}	Oscillator frequency	FSP/LCP		8		40	MHz
$g_{mXOSCHS}$	Driver Transconductance	LCP			23		mA/V
		FSP			33		
V_{XOSCHS}	Oscillation Amplitude	LCP	8 MHz		1.0		V_{PP}
			16 MHz		1.0		
			40 MHz		0.8		
$T_{XOSCHSSU}$	Startup time	FSP/LCP	8 MHz		2		ms
			16 MHz		1		
			40 MHz		0.5		
	Oscillator Analog Circuit supply current	FSP	8 MHz		2.2		mA
			16 MHz		2.2		
			40 MHz		3.2		

Table continues on the next page...

Table 23. Main oscillator electrical characteristics (continued)

Symbol	Parameter	Mode	Conditions	Min	Typ	Max	Unit
		LCP	8 MHz		141		uA
			16 MHz		252		
			40 MHz		518		
V _{IH}	Input High level CMOS Schmitt trigger	EXT Wave	Oscillator supply=3.3	1.95			V
V _{IL}	Input low level CMOS Schmitt trigger	EXT Wave	Oscillator supply=3.3			1.25	V

6.2.2 32 kHz Oscillator electrical specifications

Table 24. 32 kHz oscillator electrical specifications

Symbol	Parameter	Condition	Min	Typ	Max	Unit
f _{osc_lo}	Oscillator crystal or resonator frequency		32		40	KHz
t _{cst}	Crystal Start-up Time ^{1, 2}				2	s

1. This parameter is characterized before qualification rather than 100% tested.
2. Proper PC board layout procedures must be followed to achieve specifications.

6.2.3 16 MHz RC Oscillator electrical specifications

Table 25. 16 MHz RC Oscillator electrical specifications

Symbol	Parameter	Conditions	Value			Unit
			Min	Typ	Max	
F _{Target}	IRC target frequency	—	—	16	—	MHz
PTA	IRC frequency variation after trimming	—	-5	—	5	%
T _{startup}	Startup time	—		—	1.5	us
T _{STJIT}	Cycle to cycle jitter		—	—	1.5	%
T _{LTJIT}	Long term jitter		—	—	0.2	%

NOTE

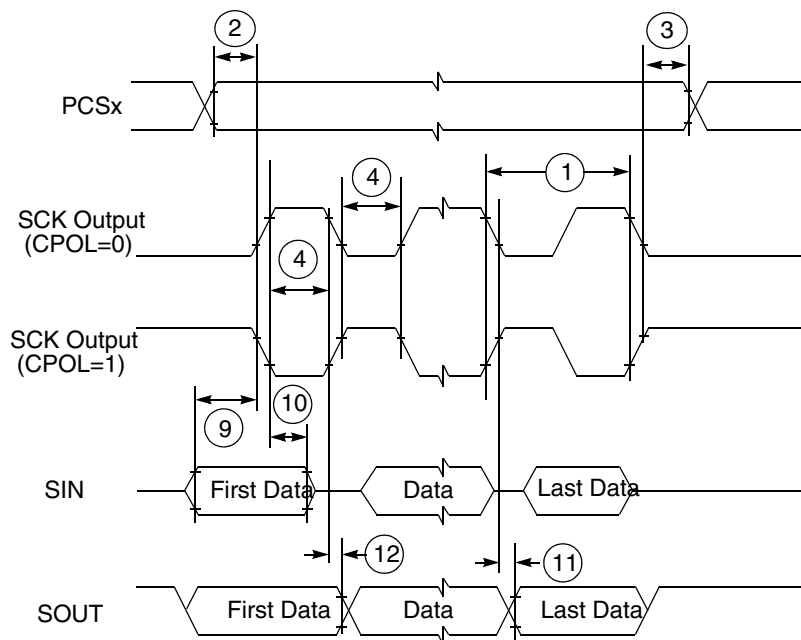
The above start up time of 1 us is equivalent to 16 cycles of 16 MHz.

Table 36. Continuous SCK timing

Spec	Characteristics	Pad Drive/Load	Value	
			Min	Max
tSCK	SCK cycle timing	strong/50 pF	100 ns	-
-	PCS valid after SCK	strong/50 pF	-	15 ns
-	PCS valid after SCK	strong/50 pF	-4 ns	-

Table 37. DSPI high speed mode I/Os

DSPI	High speed SCK	High speed SIN	High speed SOUT
DSPI2	GPIO[78]	GPIO[76]	GPIO[77]
DSPI3	GPIO[100]	GPIO[101]	GPIO[98]
SPI1	GPIO[173]	GPIO[175]	GPIO[176]
SPI2	GPIO[79]	GPIO[110]	GPIO[111]

**Figure 8. DSPI classic SPI timing — master, CPHA = 0**

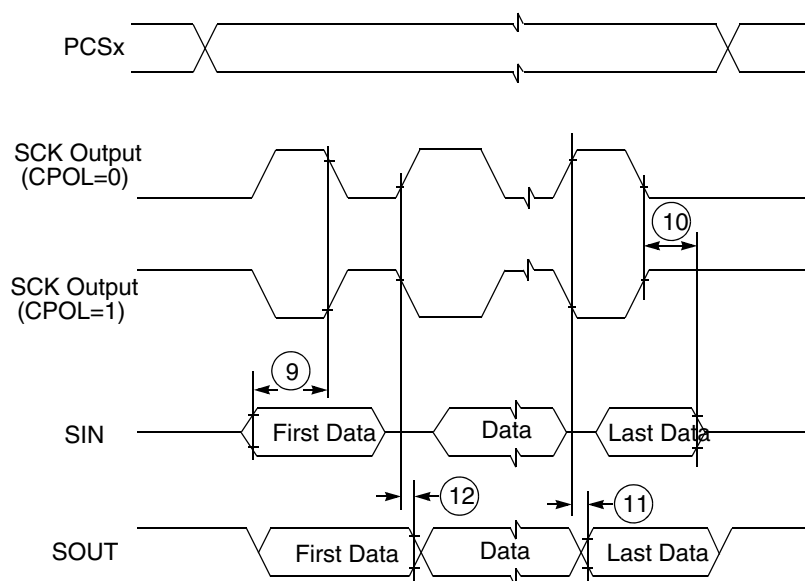


Figure 9. DSPI classic SPI timing — master, CPHA = 1

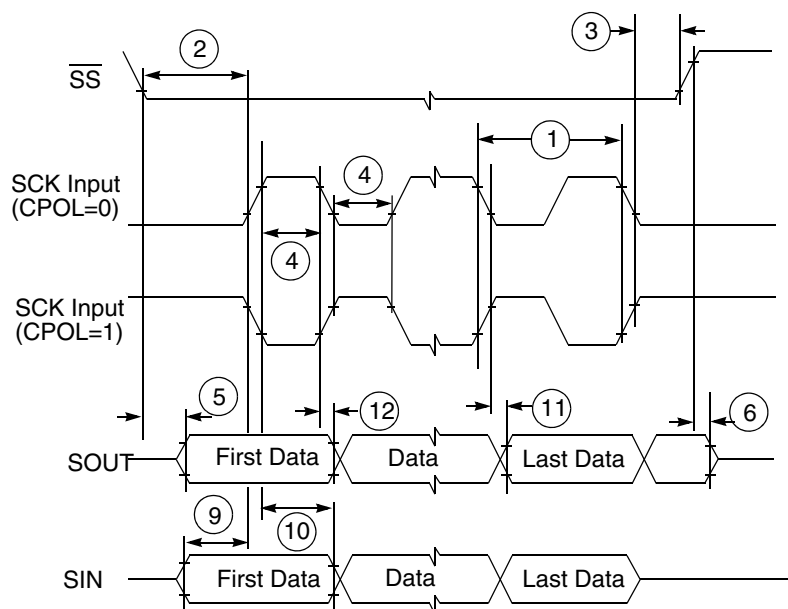


Figure 10. DSPI classic SPI timing — slave, CPHA = 0

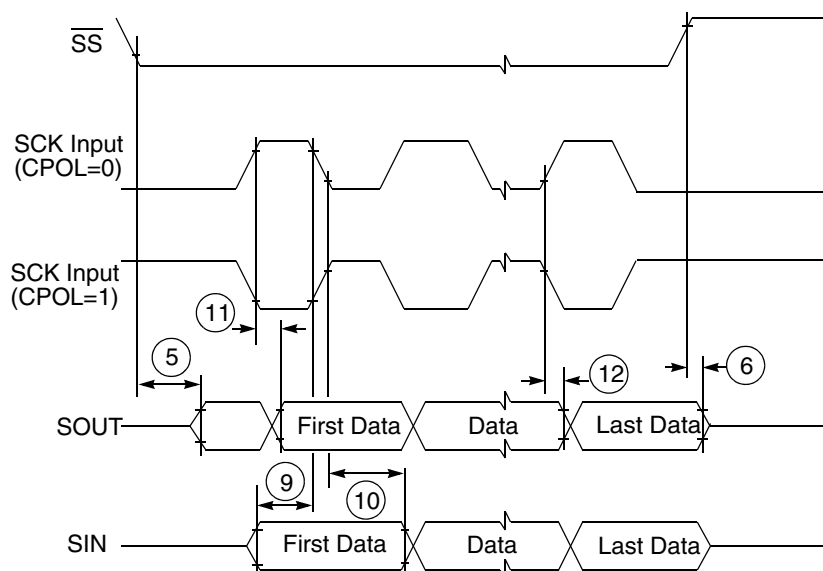


Figure 15. DSPI modified transfer format timing — slave, CPHA = 1

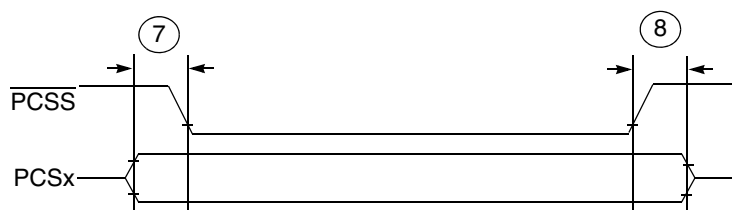


Figure 16. DSPI PCS strobe (PCSS) timing

6.4.2 FlexRay electrical specifications

6.4.2.1 FlexRay timing

This section provides the FlexRay Interface timing characteristics for the input and output signals. It should be noted that these are recommended numbers as per the FlexRay EPL v3.0 specification, and subject to change per the final timing analysis of the device.

MediaLB (MLB) electrical specifications

Ground = 0.0 V; Load Capacitance = 60 pF, input transition= 1 ns ; MediaLB speed = 256/512 Fs; Fs = 48 kHz; all timing parameters specified from the valid voltage threshold as listed below; unless otherwise noted.

Table 45. MLB 3-Pin 256/512 Fs Timing Parameters

Parameter	Symbol	Min	Max	Unit	Comment
MLBCLK operating frequency	f_{mck}	11.264	25.6	MHz	256xFs at 44.0 kHz, 512xFs at 50.0 kHz
MLBCLK rise time	t_{mckr}		3	ns	V_{IL} to V_{IH}
MLBCLK fall time	t_{mckf}		3	ns	V_{IH} to V_{IL}
MLBCLK low time ¹	t_{mckl}	30 14	—	ns	256xFs 512xFs
MLBCLK high time	t_{mckh}	30 14	—	ns	256xFs 512xFs
MLBSIG/MLBDAT receiver input setup to MLBCLK falling	t_{dsmcf}	1	—	ns	—
MLBSIG/MLBDAT receiver input hold from MLBCLK low	t_{dhmcf}	t_{mcfdz}	—	ns	—
MLBSIG/MLBDAT output valid from MLBCLK low	t_{mcfdz}	0	t_{mckl}	ns	2
Bus output hold from MLBCLK low	t_{mdzh}	4	—	ns	2

1. MLBCLK low/high time includes the pluse width variation.
2. The MediaLB driver can release the MLBDAT/MLBSIG line as soon as MLBCLK is low; however, the logic state of the final driven bit on the line must remain on the bus for t_{mdzh} . Therefore, coupling must be minimized while meeting the maximum load capacitance listed.

Ground = 0.0 V; Load Capacitance = 40 pF, input transition= 1 ns; MediaLB speed = 1024 Fs; Fs = 48 kHz; all timing parameters specified from the valid voltage threshold as listed below; unless otherwise noted.

Table 46. MLB 3-Pin 1024 Fs Timing Parameters

Parameter	Symbol	Min	Max	Unit	Comment
MLBCLK Operating Frequency ¹	f_{mck}	45.056 -	- 51.2	MHz MHz	1024 x fs at 44.0 kHz 1024 x fs at 50.0 kHz
MLBCLK rise time	f_{mckr}		1	ns	V_{IL} to V_{IH}
MLBCLK fall time	f_{mckf}		1	ns	V_{IH} to V_{IL}
MLBCLK low time	t_{mckl}	6.1	—	ns	2
MLBCLK high time	t_{mckh}	9.3	—	ns	2
MLBSIG/MLBDAT receiver input setup to MLBCLK falling	t_{dsmcf}	1	—	ns	
MLBSIG/MLBDAT receiver input hold from MLBCLK low	t_{dhmcf}	t_{mcfdz}	—	ns	
MLBSIG/MLBDAT output valid from MLBCLK low	t_{mcfdz}	0	t_{mckl}	ns	3
Bus Hold from MLBCLK low	t_{mdzh}	2	—	ns	3

1. The controller can shut off MLBCLK to place MediaLB in a low-power state. Depending on the time the clock is shut off, a runt pulse can occur on MLBCLK.
2. MLBCLK low/high time includes the pluse width variation.
3. The MediaLB driver can release the MLBDAT/MLBSIG line as soon as MLBCLK is low; however, the logic state of the final driven bit on the line must remain on the bus for tmdzh. Therefore, coupling must be minimized while meeting the maximum load capacitance listed.

6.4.6 USB electrical specifications

6.4.6.1 USB electrical specifications

The USB electricals for the USB On-the-Go module conform to the standards documented by the Universal Serial Bus Implementers Forum. For the most up-to-date standards, visit <http://www.usb.org>.

6.4.6.2 ULPI timing specifications

The ULPI interface is fully compliant with the industry standard UTMI+ Low Pin Interface. Control and data timing requirements for the ULPI pins are given in the following table. These timings apply to synchronous mode only. All timings are measured with respect to the clock as seen at the USB_CLKIN pin.

Table 47. ULPI timing specifications

Num	Description	Min.	Typ.	Max.	Unit
	USB_CLKIN operating frequency	—	60	—	MHz
	USB_CLKIN duty cycle	—	50	—	%
U1	USB_CLKIN clock period	—	16.67	—	ns
U2	Input setup (control and data)	5	—	—	ns
U3	Input hold (control and data)	1	—	—	ns
U4	Output valid (control and data)	—	—	9.5	ns
U5	Output hold (control and data)	1	—	—	ns

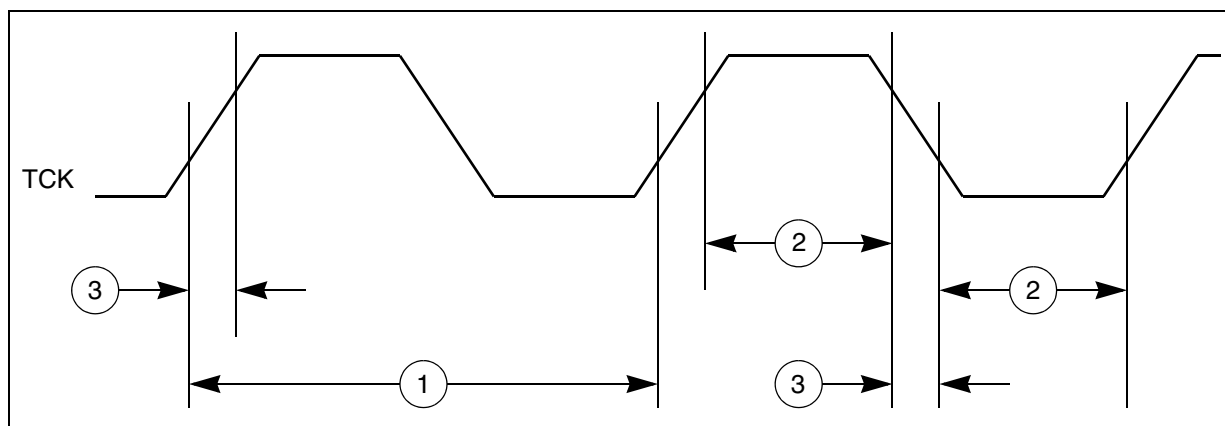


Figure 28. JTAG test clock input timing

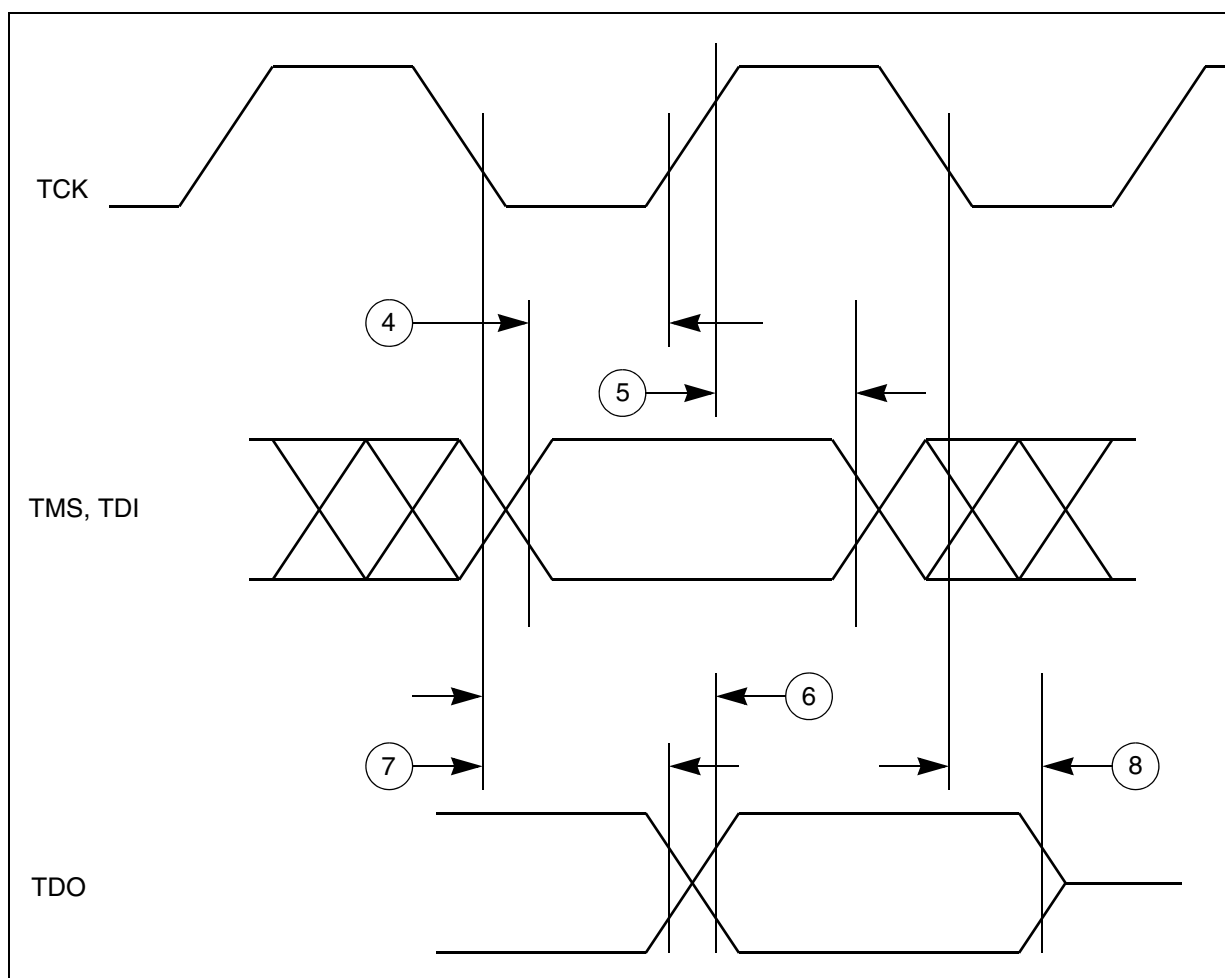


Figure 29. JTAG test access port timing

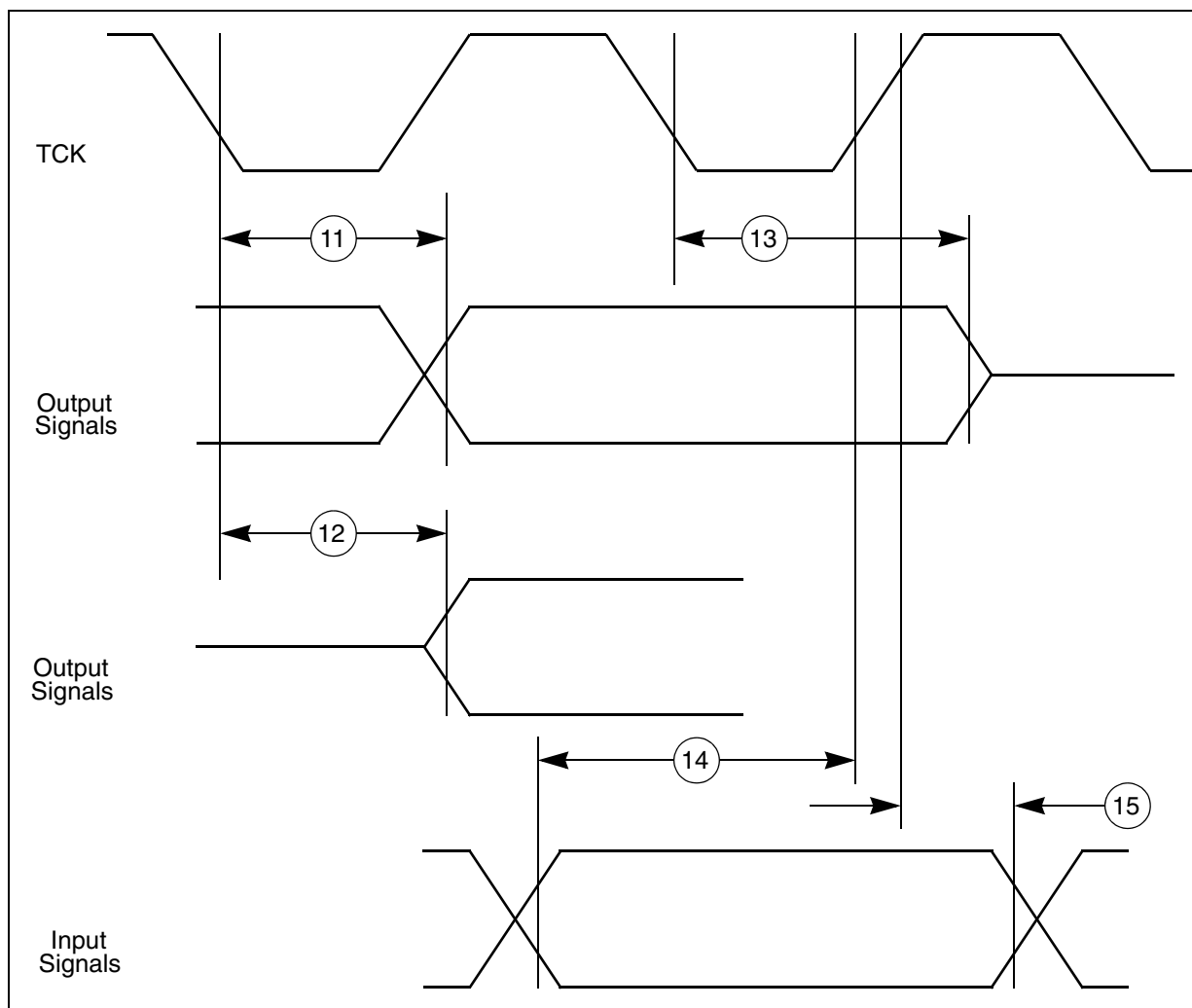


Figure 30. JTAG boundary scan timing

6.5.2 Nexus timing

Table 51. Nexus debug port timing ¹

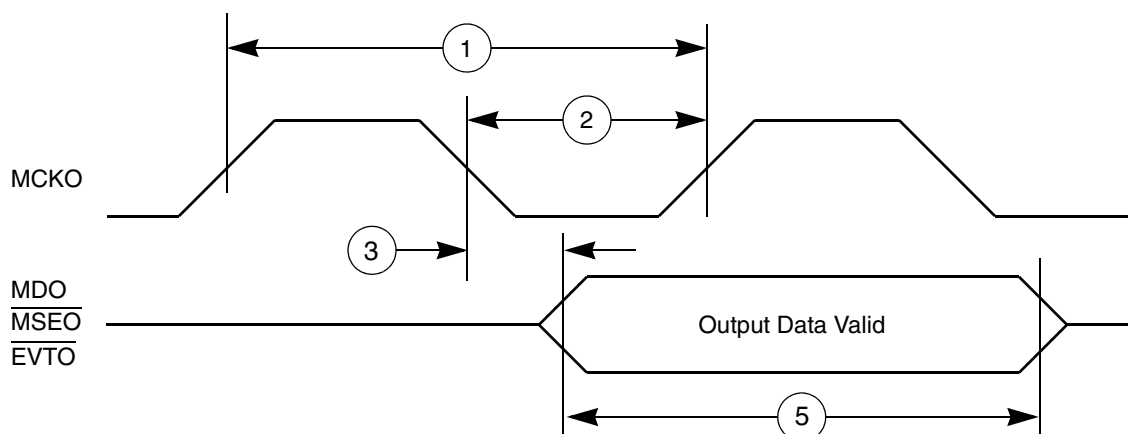
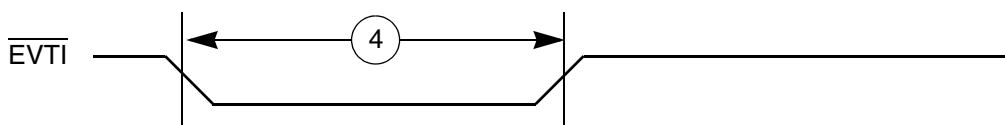
No.	Symbol	Parameter	Conditions	Min	Max	Unit
1	t_{MCYC}	MCKO Cycle Time	—	15.6	—	ns
2	t_{MDC}	MCKO Duty Cycle	—	40	60	%
3	t_{MDOV}	MCKO Low to MDO, MSEO, EVTO Data Valid ²	—	-0.1	0.25	t_{MCYC}
4	t_{EVTIPW}	EVTI Pulse Width	—	4	—	t_{TCYC}
5	t_{EVTOPW}	EVTO Pulse Width	—	1	—	t_{MCYC}
6	t_{TCYC}	TCK Cycle Time ³	—	62.5	—	ns
7	t_{TDC}	TCK Duty Cycle	—	40	60	%
8	t_{NTDIS} , t_{NTMSS}	TDI, TMS Data Setup Time	—	8	—	ns

Table continues on the next page...

Table 51. Nexus debug port timing ¹ (continued)

No.	Symbol	Parameter	Condition s	Min	Max	Unit
9	t_{NTDIH} , t_{NTMSH}	TDI, TMS Data Hold Time	—	5	—	ns
10	t_{JOV}	TCK Low to TDO/RDY Data Valid	—	0	25	ns

1. JTAG specifications in this table apply when used for debug functionality. All Nexus timing relative to MCKO is measured from 50% of MCKO and 50% of the respective signal.
2. For all Nexus modes except DDR mode, MDO, $\overline{\text{MSEO}}$, and $\overline{\text{EVTO}}$ data is held valid until next MCKO low cycle.
3. The system clock frequency needs to be four times faster than the TCK frequency.

**Figure 31. Nexus output timing****Figure 32. Nexus EVTI Input Pulse Width**

Thermal attributes

Board type	Symbol	Description	176LQFP	Unit	Notes
—	Ψ_{JT}	Thermal characterization parameter, junction to package top	0.2	°C/W	7

1. Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance
2. Per SEMI G38-87 and JEDEC JESD51-2 with the single layer board horizontal.
3. Per JEDEC JESD51-6 with the board horizontal.
4. Thermal resistance between the die and the printed circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.
5. Thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1).
6. Thermal resistance between the die and the solder pad on the bottom of the package based on simulation without any interface resistance.
7. Thermal characterization parameter indicating the temperature difference between package top and the junction temperature per JEDEC JESD51-2.

Board type	Symbol	Description	324 MAPBGA	Unit	Notes
Single-layer (1s)	$R_{\theta JA}$	Thermal resistance, junction to ambient (natural convection)	25.5	°C/W	1, 2
Four-layer (2s2p)	$R_{\theta JA}$	Thermal resistance, junction to ambient (natural convection)	19.0	°C/W	1,23
Single-layer (1s)	$R_{\theta JMA}$	Thermal resistance, junction to ambient (200 ft./min. air speed)	18.1	°C/W	1, 3
Four-layer (2s2p)	$R_{\theta JMA}$	Thermal resistance, junction to ambient (200 ft./min. air speed)	14.8	°C/W	1,3
—	$R_{\theta JB}$	Thermal resistance, junction to board	10.4	°C/W	4
—	$R_{\theta JC}$	Thermal resistance, junction to case	8.4	°C/W	5
—	Ψ_{JT}	Thermal characterization parameter, junction to package top natural convection)	0.45	°C/W	6
—	Ψ_{JB}	Thermal characterization parameter, junction to package top natural convection)	2.65	°C/W	7

1. Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.,
2. Per JEDEC JESD51-2 with the single layer board horizontal. Board meets JESD51-9 specification.
3. Per JEDEC JESD51-6 with the board horizontal
4. Thermal resistance between the die and the printed circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.
5. Thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1).
6. Thermal characterization parameter indicating the temperature difference between package top and the junction temperature per JEDEC JESD51-2.
7. Thermal characterization parameter indicating the temperature difference between package bottom center and the junction temperature per JEDEC JESD51-12. When Greek letters are not available, the thermal characterization parameter is written as Psi-JB.

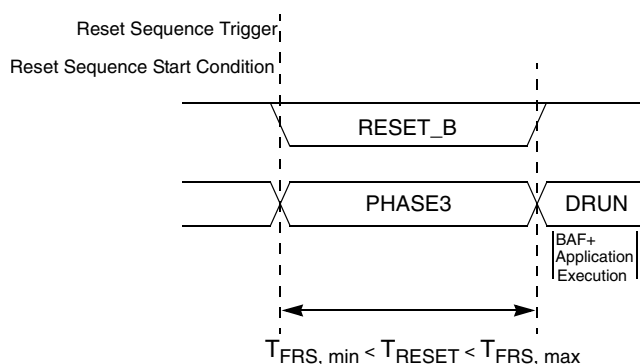


Figure 39. Functional reset sequence short

The reset sequences shown in [Figure 38](#) and [Figure 39](#) are triggered by functional reset events. RESET_B is driven low during these two reset sequences only if the corresponding functional reset source (which triggered the reset sequence) was enabled to drive RESET_B low for the duration of the internal reset sequence. See the RGM_FBRE register in the device reference manual for more information.

11 Revision History

The following table provides a revision history for this document.

Table 56. Revision History

Rev. No.	Date	Substantial Changes
1	14 March 2013	Initial Release
1.1	16 May 2013	Updated Pinouts section
2	22 May 2014	- Removed Category (SR, CC, P, T, D, B) column from all the table of the Datasheet - Revised the feature list. - Revised Introduction section to remove classification information. - Updated optional information in the ordering information figure. - Revised Absolute maximum rating section: - Removed category column from table - Added footnote at Ta - Revised Recommended operating conditions section - Added notes - Updated table: Recommended operating conditions (VDD_HV_x = 3.3 V) - Updated table: Recommended operating conditions (VDD_HV_x = 5 V) - Revised Voltage regulator electrical characteristics - Updated text describing bipolar transistors - Updated figure: Voltage regulator capacitance connection - Updated table: Voltage regulator electrical specifications - Removed Brownout information - Revised Voltage monitor electrical characteristics table
		- Revised Supply current characteristics section - Updated table: Current consumption characteristics - Updated table: Low Power Unit (LPU) Current consumption characteristics - STANDBY Current consumption characteristics

Table continues on the next page...

Table 56. Revision History (continued)

Rev. No.	Date	Substantial Changes
		- In table: Functional Pad AC Specifications @ 3.3 V Range - Updated values for symbol 'pad_sr_hv (output)' - In table: DC electrical specifications @ 3.3V Range - Updated values for VDD_HV_x, Vih, Vhys - Added Vih (pad_i_hv), Vil (pad_i_hv), Vhys (pad_i_hv), Vih_hys, Vil_hys - In table: Functional Pad AC Specifications @ 5 V Range - Updated values for symbol 'pad_sr_hv (output)' - In table DC electrical specifications @ 5 V Range - Added Vih (pad_i_hv), Vil (pad_i_hv), Vhys (pad_i_hv), Vih_hys, Vil_hys
		- In section: PORST electrical specifications - In table: PORST electrical specifications - Updated 'Min' value for $W_{NF\text{PORST}}$ - Corrected 'Unit' for V_{IH} and V_{IL} - In section: Peripheral operating requirements and behaviours - Revised table: ADC conversion characteristics (for 12-bit) and ADC conversion characteristics (for 10-bit) - In section: Analogue Comparator (CMP) electrical specifications - In table: Comparator and 6-bit DAC electrical specifications - Updated 'Max' value of $I_{DDL\text{S}}$ - Updated 'Min' and 'Max' for V_{AIO} and DNL - Updated 'Description' 'Min' 'Max' of V_H - Updated row for tDHS - Added row for tDLS - Removed row for VCMPOh and VCMPOI - In section: Clocks and PLL interfaces modules - Revised table: Main oscillator electrical characteristics - In table: 16 MHz RC Oscillator electrical specifications - Updated 'Max' of Tstartup - In table: 128 KHz Internal RC oscillator electrical specifications - Removed Uncalibrated 'Condition' for Fosc - Updated 'Min' and 'Max' of Calibrated Fosc - Updated 'Temperature dependence' and 'Supply dependence' - In table: PLL electrical specifications - Removed Input Clock Low Level, Input Clock High Level, Power consumption, Regulator Maximum Output Current, Analog Supply, Digital Supply (VDD_LV), Modulation Depth (Down Spread), PLL reset assertion time, and Power Consumption - Removed 'Typ' value of Duty Cycle at pllclkout - Removed 'Min' from calibration mode of Lock Time - In table: Jitter calculation - Added 1 Sigma Random Jitter value for Long term jitter
		- In section Flash read wait state and address pipeline control settings - Revised table: Flash Read Wait State and Address Pipeline Control - Removed section: On-chip peripherals - Added section: 'Reset sequence'
Rev4	Feb 10 2017	- Added VDD_HV_BALLAST footnote in Voltage regulator electrical characteristics - Added Note to clarify In-Rush current and pin capacitance in Voltage regulator electrical characteristics - Updated SIUL2_MSCRN[Src 1:0]=11 @25pF max value; SIUL2_MSCRN[Src 1:0]=11 @50pF min value; SIUL2_MSCRN[Src 1:0]=10 @25pF min and max values in AC specifications @ 3.3 V Range

Table continues on the next page...

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